Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
0.371 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
Between 0.215 inch	es and 0.265 inches
Electrode Internall	y-electrically Connected To Case:
Cathode	
Mounting Method:	
Terminal	
Features Provided	
Hermetically sealed	case
Semiconductor Ma	iterial:
Silicon	
Voltage Rating In V	/olts Per Characteristic:
51.0 regulator volta	age
Voltage Tolerance	In Percent:
-5.0/+5.0	
Current Rating Per	Characteristic:
5.00 milliamperes se	purce cutoff current horsepower metric and 18.00 milliamperes repetitive peak forward current
Power Rating Per (Characteristic:
1.0 watts small-sign	al input power, common-collector preset
Maximum Operatir	ng Tempurature Per Measurement Point:
175.0 degrees celsi	us ambient air
Test Data Docume	nt:
81349-mil-s-19500 s	specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specificatior
format; excludes cc	mmercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and p	performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And	I Quantity:
2 uninsulated wire le	ead
Specification Data:	
81349-mil-s-19500/ ⁻	115 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	